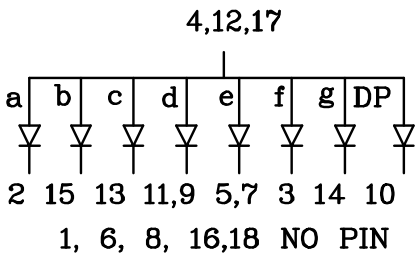
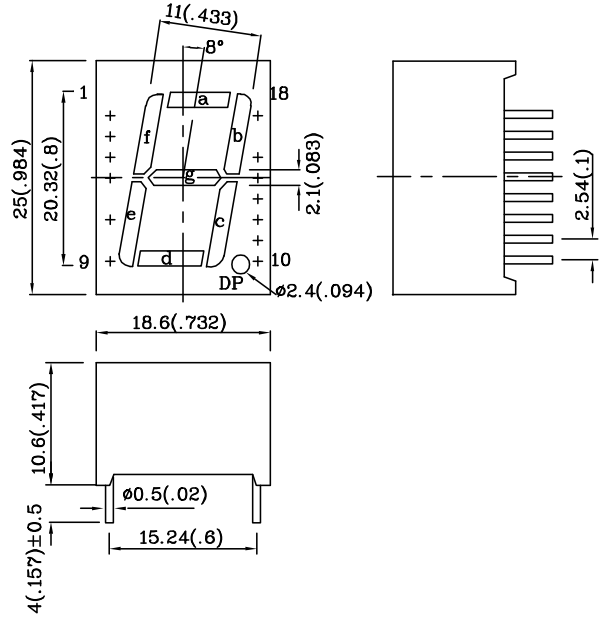


Features

- 0.8 INCH DIGIT HEIGHT.
- LOW CURRENT OPERATION.
- EXCELLENT CHARACTER APPEARANCE.
- HIGH LIGHT OUTPUT.
- EASY MOUNTING ON P.C. BOARDS OR SOCKETS.
- I.C. COMPATIBLE.
- MECHANICALLY RUGGED.
- STANDARD : GRAY FACE, WHITE SEGMENT.
- RoHS COMPLIANT.



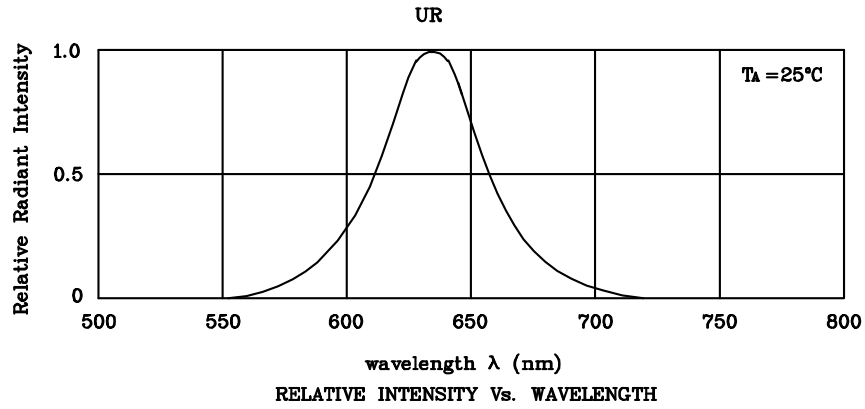
Notes:

1. All dimensions are in millimeters (inches).
2. Tolerance is $\pm 0.25(0.01)$ " unless otherwise noted.

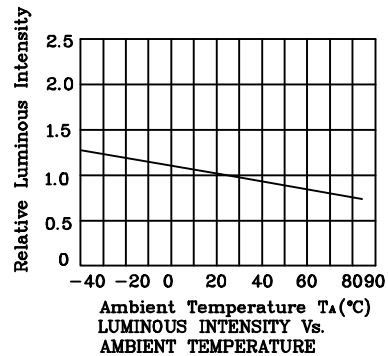
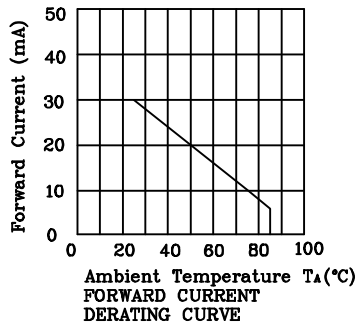
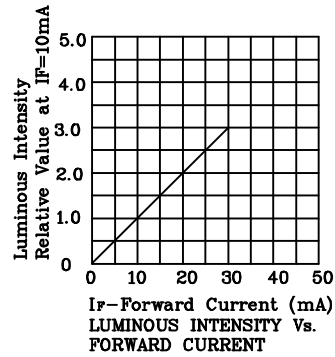
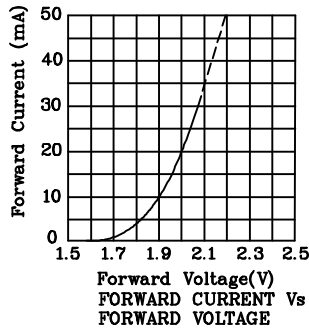
Absolute Maximum Ratings (TA=25°C)		UR (GaAsP/GaP)	Unit
Reverse voltage	VR	5	V
Forward current	IF	30	mA
Forward current (peak) 1/10Duty cycle 0.1ms pulse width	iFS	160	mA
Power dissipation	PT	105	mW
Operating temperature	TA	-40 ~ +85	°C
Storage temperature	Tstg	-40 ~ +85	
Lead solder temperature [2mm below package base]	260°C For 5 Seconds		

Operating Characteristics (TA=25°C)		UR (GaAsP/GaP)	Unit
Forward Voltage (Typ.) (IF=10mA)	VF	1.9	V
Forward Voltage (Max.) (IF=10mA)	VF	2.5	V
Reverse Current (VR=5V)	IR	10	uA
Wavelength of Peak Emission (IF=10mA)	λ peak	627	nm
Wavelength of Dominant Emission (IF=10mA)	λ D	625	nm
Spectral Line Full Width At Half-Maximum (IF=10mA)	$\Delta\lambda$	45	nm
Capacitance (VF=0V, f=1MHz)	C	15	pF

Part Number	Emitting Color	Emitting Material	Luminous Intensity (IF=10mA) ucd		Wavelength nm λ P	Description
			min.	typ.		
XDUR20A-1	Red	GaAsP/GaP	1200	6390	627	Common Anode, Rt. Hand Decimal
Published Date : MAY.25.2005 Drawing No : XDSA0331 V5 Checked : Shin Chi P.1/3						

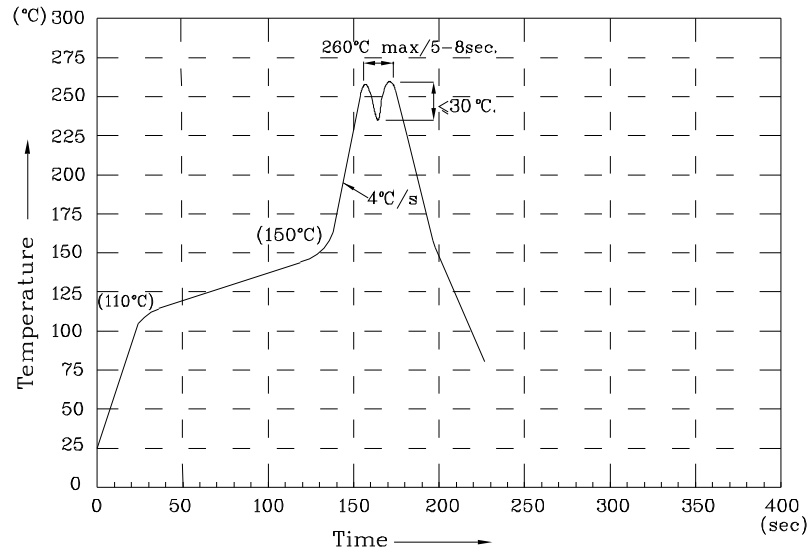


❖ UR



XDUR20A-1

Wave Soldering Profile For Lead-free Through-hole LED.



NOTES:

- 1.Recommend the wave temperature 245°C~260°C.The maximum soldering temperature should be less than 260°C.
- 2.Do not apply stress on epoxy resins when temperature is over 85 degree°C.
- 3.The soldering profile apply to the lead free soldering (Sn/Cu/Ag alloy).
- 4.No more than once.

Remarks:

If special sorting is required (e.g. binning based on forward voltage, luminous intensity, or wavelength), the typical accuracy of the sorting process is as follows:

1. Wavelength: +/-1nm
2. Luminous Intensity: +/-15%
3. Forward Voltage: +/-0.1V

Note: Accuracy may depend on the sorting parameters.